

# 42510ESDA-TR1

## Four channel ultra low capacitance ESD Suppressor









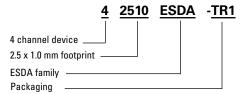
#### **Product features**

- Ultra low capacitance ESD suppressor ideally suited for protecting high speed data applications with virtually no signal distortion
- Four channel, bi-directional device helps provide significant PCB layout space savings and trace layout complexity
- Maintains an extremely low leakage current at rated voltage
- Provides ESD protection with fast response time (<1 ns) allowing equipment to pass IEC 61000-4-2 level 4 test
- Matches footprint of common higher capacitance DFN2510-10 TVS diode packages

#### **Applications**

- · Laptops, notebooks, desktop
- HDTV, set top box
- · GPS and Bluetooth communication antenna
- USB 2.0, 3.0 and 3.1
- HDMI 1.3, 1.4a, 2.0
- DisplayPort ™
- · SATA and eSATA

#### Ordering part number



#### Package suffix

-TR1: 5000 parts on a 7" diameter reel

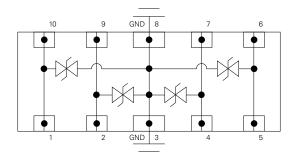
#### **Product specifications**

Electrical specifications	Minimum	Typical	Maximum	Units
Rated voltage			12	Vdc
Trigger voltage <sup>2</sup>		300		Vdc
Clamping voltage <sup>1</sup>		30		Vdc
Capacitance @ 1 MHz		0.1		pF
Leakage current @ 12 Vdc		0.01		uA
Response time		0.1		ns
ESD Voltage capability to IEC6100-4-2 (contact)	10			kV
ESD Voltage capability to IEC6100-4-2 (air)	15			kV
ESD withstand pulses		1000		Number of pulses

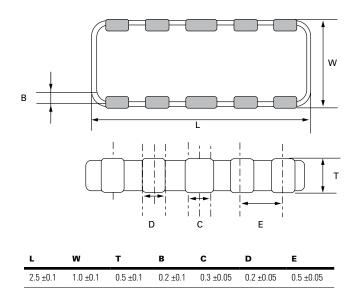
- 1. Maximum peak voltage with a 8/20 µs waveform and a 1 A pulse current per IEC 61000-4-2 level 4
- 2. Trigger voltage: Trigger measurement made using Transmission Line Pulse (TLP) method.



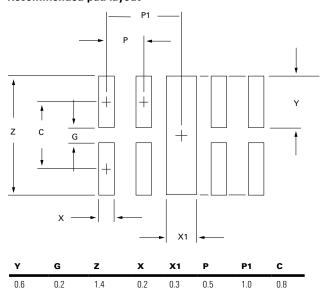
## **Equivelent circuit**



## Dimensions-mm



#### Recommended pad layout



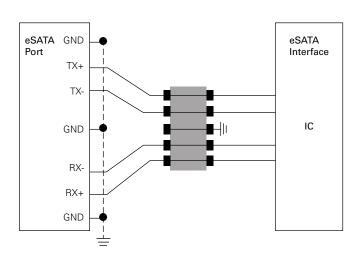
## **General specifications**

Operating temperature: - 55 °C to +125 °C	
Storage temperature (component): - 55 °C to +125 °C	
High temperature load voltage: +125 °C for 1000 hours at rated voltage	
Thermal shock: 100 cycles, -55 °C to +125 °C, 30 minuets dwell time	
Resistance to solder heat: +260 °C ±5 °C 10 seconds	
Moisture sensitivity level (MSL): 1	

## **HDMI** layout

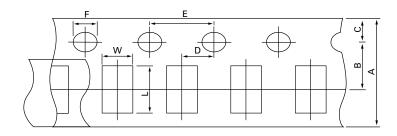
#### HDMI Port **HDMI** Chipset D2+ • Ground D2-D1+ **Outside World** • Ground • D1-D0+ Ground D0-CLK+ Ground CLK-Case Signal Ground Ground Ground

## eSATA layout



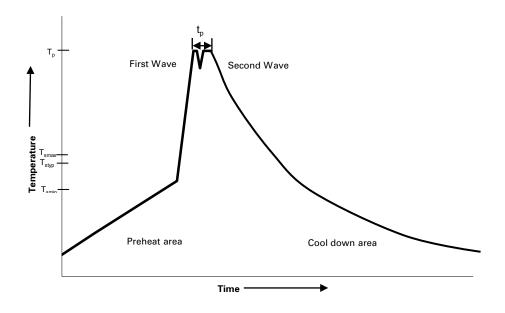
#### Packaging information- mm

Supplied in tape and reel packaging, 5000 parts per seven inch (178 mm) reel per EIA Standard 481-1



Α	В	С	D	E	F	L	W
8.0 ±0.30	3.50 ±0.05	1.75 ±0.10	2.00 ±0.05	4.00 ±0.10	1.5 ±0.10	2.9 ±0.20	1.40 ±0.20

## Wave solder profile



#### Reference EN 61760-1:2006

Profile feature		Standard SnPb solder	Lead (Pb) free solder
Preheat	• Temperature min. (T <sub>smin</sub> )	100 °C	100 °C
	Temperature typ. (T <sub>styp</sub> )	120 °C	120 °C
	• Temperature max. (T <sub>smax</sub> )	130 °C	130 °C
-	Time (T <sub>smin</sub> to T <sub>smax</sub> ) (t <sub>s</sub> )	70 seconds	70 seconds
$\Delta$ preheat to	max Temperature	150 °C max.	150 °C max.
Peak tempera	ature (T <sub>P</sub> )*	235 °C − 260 °C	250 °C − 260 °C
Time at peak	temperature (t <sub>p</sub> )	10 seconds max 5 seconds max each wave	10 seconds max 5 seconds max each wave
Ramp-down r	ate	~ 2 K/s min ~3.5 K/s typ ~5 K/s max	~ 2 K/s min ~3.5 K/s typ ~5 K/s max
Time 25 °C to	25 °C	4 minutes	4 minutes

#### Manual solder

+280 °C (3 seconds maximum by soldering iron), generally manual/hand soldering is not recommended.

#### Solder reflow profile

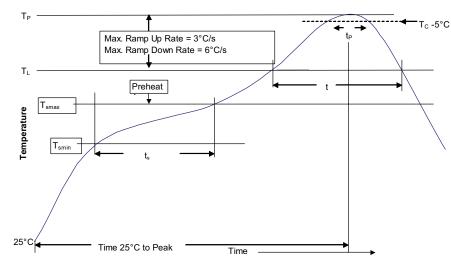


Table 1 - Standard SnPb solder (T<sub>C</sub>)

Package thickness	Volume mm3 <350	Volume mm3 ≥350
<2.5 mm)	235 °C	220 °C
≥2.5 mm	220 °C	220 °C

Table 2 - Lead (Pb) free solder (T<sub>C</sub>)

Package thickness	Volume mm³ <350	Volume mm³ 350 - 2000	Volume mm³ >2000
<1.6 mm	260 °C	260 °C	260 °C
1.6 – 2.5 mm	260 °C	250 °C	245 °C
>2.5 mm	250 °C	245 °C	245 °C

#### Reference J-STD-020

Profile feature	Standard SnPb solder	Lead (Pb) free solder
Preheat and soak • Temperature min. (T <sub>smin</sub> )	100 °C	150 °C
• Temperature max. (T <sub>smax</sub> )	150 °C	200 °C
• Time (T <sub>Smin</sub> to T <sub>Smax</sub> ) (t <sub>S</sub> )	60-120 seconds	60-120 seconds
Ramp up rate $T_L$ to $T_p$	3 °C/ second max.	3 °C/ second max.
Liquidous temperature (TL) Time (t <sub>L</sub> ) maintained above $T_L$	183 °C 60-150 seconds	217 °C 60-150 seconds
Peak package body temperature (Tp)*	Table 1	Table 2
$\overline{\text{Time } (t_p)^* \text{ within 5 °C of the specified classification temperature } (T_c)}$	20 seconds*	30 seconds*
Ramp-down rate (T <sub>p</sub> to T <sub>L</sub> )	6 °C/ second max.	6 °C/ second max.
Time 25 °C to peak temperature	6 minutes max.	8 minutes max.

<sup>\*</sup> Tolerance for peak profile temperature (Tp) is defined as a supplier minimum and a user maximum.

Life Support Policy: Eaton does not authorize the use of any of its products for use in life support devices or systems without the express written approval of an officer of the Company. Life support systems are devices which support or sustain life, and whose failure to perform, when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user.

Eaton reserves the right, without notice, to change design or construction of any products and to discontinue or limit distribution of any products. Eaton also reserves the right to change or update, without notice, any technical information contained in this bulletin.

Eaton Electronics Division 1000 Eaton Boulevard Cleveland, OH 44122

Cleveland, OH 44122 United States Eaton.com/electronics

© 2021 Eaton All Rights Reserved Printed in USA Publication No. 4378 March 2021

Eaton is a registered trademark.

All other trademarks are property of their respective owners.

Follow us on social media to get the latest product and support information.









